High Linearity SQIF-like Josephson-Junction Structures

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Abstract—Recently we reported design approaches for the synthesis of multi-SQUID structures capable of providing high linearity voltage response. These structures were developed to form periodic voltage responses. This paper presents possible design solutions for multi-element structures providing SQIF-like high linearity voltage response. The approach is based on the use of a differential scheme of two parallel SQIFs with arrays oppositely frustrated by applied magnetic field \( \delta B \). The differential scheme enables a high efficiency synthesis of highly linear SQIF response by subtraction of deviations from linear law.

Index Terms— SQUID arrays, parallel SQIF, differential scheme, amplifiers, high linearity, dynamic range.

I. INTRODUCTION

R ecently we have reported an approach to the synthesis of multi-SQUID structures capable of providing high linearity voltage response \([1],[2]\). The approach is based on the formation of serial structures capable of providing periodic triangular voltage response to a homogeneous magnetic field \( B \) with “frequency” spectrum as follows:

\[
V(B) = \sum_k A_k \cos(k \omega_0 B), \quad A_k = A_0 \sum_k \sin^2 \left(\frac{k \omega_0 \delta B}{2}\right),
\]

where \( 2\delta B \) is width of the triangular pulse with repetition cycle \( B_1 = 2\pi/\omega_0 \). Two ways were suggested for the structure formation. The first one is to use interferometer cells (dc SQUIDs) providing harmonic voltage response with “frequency” \( k \omega_0 = (2\pi/\Phi_0) a_k \), where \( a_k \) is effective area of the interferometer cell which belongs to the \( k \)-th group. In case when input signal is a control line current \( I \) (instead of \( B \)), the effective area should be replaced by mutual inductance \( M_k \), i.e. \( k \omega_0 = (2\pi/\Phi_0) M_k \).

It is significant that spectrum of the voltage response with minimum period \( B_1 = 2\delta B \) contains only odd harmonics with amplitudes decreasing monotonically as the squared harmonic number:

\[
A(k \omega_0) = A_0 / k^2, \quad k = 2n - 1, \quad n = 1, 2, \ldots,
\]

The second way is to form a differential scheme using serial arrays of interferometer cells biased by current \( I_b = I_c \), where \( I_c \) is the interferometer critical current. Voltage response of such an array is characterized by numerous harmonics with monotonically decreasing amplitudes:

\[
A(n \omega_0) = \frac{A_0}{n^2 - 1}.
\]

Apart from a few first harmonics, the amplitude decrease law is quite close to \( 1/n^2 \). Differential scheme of two serial arrays with \( \Phi_0/2 \)-frustration provides subtraction of all even harmonics, and therefore the resulting response becomes close enough to the triangular one with \( B_1 = 2\delta B \). Fig. 1 shows schematically the differential array structure and magnetic biasing of the arrays. One can increase the linearity of the differential array voltage response. For this purpose, we should add to the array structure a few cells with sinusoidal responses generating necessary spectrum tones. These cells are dc interferometer biased well above critical current \( I_b > 2I_c \) in order to generate as close to a sinewave as possible. These additional cells are to correct the initial spectral components in (3) in order to approach the desired spectrum (2).

Now, we replace the individual interferometer cells in both serial arrays by parallel arrays and arrive to a parallel-series differential structure. In this paper we present further development of such a differential structure. Considerable increase in the voltage response linearity results from the use

Fig. 1. Differential array structure consisting of two series arrays of dc interferometers with biasing \( I_b = I_c \), where \( I_c \) – critical current of the interferometers. In one array, each cell is biased by magnetic flux \( \Phi_0/2 \). Additional flux \( \Phi_0/4 \) is applied to all cells to set the operating point.

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of parallel SQIFs [3] with synthesized array structure instead of ordinary parallel arrays with randomly chosen parameters.

II. SQIF-BASED DIFFERENTIAL STRUCTURES

A. Optimal Cell Area Distribution

Differential scheme of two parallel SQIFs oppositely frustrated by an applied magnetic field $\delta B$ (see Fig. 3) is able to provide extremely linear voltage response in case of properly synthesized SQIF structure. At vanishing inductances $l$ of the interferometer cells one can use analytical relation for the parallel SQIF response [3]-[5]:

$$ V(B) = V_c \left[ (I_b / I_c)^2 - |S_K(B)|^2 \right] $$

(4)

where $S_K(B)$ is structural factor:

$$ S_K(B) = \frac{1}{K} \sum_{k=1}^{K} \exp \left( \frac{2\pi k}{\Phi_0} \sum_{m=1}^{K} a_m \right) $$

(5)

$I_b$ – bias current, $I_c$ – total critical current, $K$ – number of Josephson junctions, $a_m$ – area of the $m$-th interferometer cell. At sufficiently high number $K$ one can use integration instead of summation, and relation (5) can be transformed as follows:

$$ S(B) = \frac{1}{L} \int_0^L dz \exp \left( \frac{2\pi}{\Phi_0} B^z \int_0^x a(x)dx \right) $$

(6)

We need to find the specific distribution of the interferometer cell areas $a(x)$ along SQIF-structure $(0 < x < L)$ to make the differential circuit voltage response

$$ \Delta V(B) = V(B + \delta B) - V(B - \delta B) $$

(7)

close to a linear law

$$ \Delta V(B) = k \cdot B $$

(8)

in a signal region $-\alpha \delta B < B < \alpha \delta B$, where $\alpha \leq 1$.

Relations (2)-(6) allow deriving master equations and stating minimization problem for the obtained functional in order to find an optimal distribution $a(x)$. One can use an iterative algorithm to find the problem solution, starting from some initial approximation (Fig. 2). In case of finite inductances $l$ of the interferometer cells, the SQIF response $V(B)$ has to be calculated by means of numerical simulation, using, e.g., PSCAN simulation package [6].

The problem can have more than one solution. We have found some analytical approximations for solutions at $l = 0$; the best one is shown below:

$$ a(x)/a_\Sigma = 1.2 - 0.48 \sin^3(\pi x), $$

(9)

where $a_\Sigma$ - total area of SQIF.

B. Response Linearity

Fig. 4 shows both the cell area distribution (9) and the differential circuit voltage response. The linearity of the voltage response within the shaded central area reaches 101 dB. To estimate the linearity, we applied $sin$-like input signal and then studied spectrum of output signal. The ratio of the fundamental to the highest spur was used to characterize the response linearity. It was found that the high linearity can be obtained using relatively small number $N$ of SQIF cells with the cell areas fitted to (9). Fig. 5a shows that the linearity increases rapidly with number $N$ and at $N > 35$ reaches a
plateau where the linearity is about 101 dB. As for the impact of fabrication spread in the cell areas, Fig. 5b shows that the tolerable spread is about 4% at N = 36; and then the linearity decreases with the spread value. Approximately the same result was obtained for spread in critical currents of Josephson junctions. Larger number of N can be used in order to decrease impact of the fabrication spread in the SQIF circuit parameters as well as to increase dynamic range proportional to $N^{1/2}$ up to the linearity level obtained.

C. Two-Dimensional Structure

Both the dynamic range and the output signal amplitude can be additionally increased by connection of the differential SQIF structures in series, i.e., by integrating a two-dimensional differential serial-parallel SQIF structure (see Fig. 5). The number $K$ of the elements connected in series is responsible for the output signal amplitude, while tonal number of Josephson junctions $N^* = N \cdot K$ is responsible for dynamic range of the structure. Varying the number of elements connected in parallel ($N$) and in series ($K$), one can change impedance of the structure in wide range.

III. INDUCTANCE INFLUENCE

A. From Model to Real Structure

There are several problems which should be solved in order to realize the potentially high performance of two-dimensional SQIF structures. One should note that the optimally synthesized structure of parallel SQIF was derived using the RSJ model of Josephson junctions and also assuming vanishing coupling inductances ($L = 0$). This means that the performance of real SQIF structures will likely to be lower. One can suggest three approaches of preserving the expected high performance: (i) to provide the closest approach of the experimental Josephson junction characteristics to the ones given by RSJ model, (ii) to synthesize an optimal SQIF structure based on experimental Josephson junction characteristics and unavoidable circuit parasitics using numerical simulation technique and iterative algorithm (Fig. 2), and (iii) to utilize circuit techniques to minimize impact of parasitic parameters to the overall circuit performance. In all probability, an optimal strategy should be based on combination of all these approaches.

B. Shunting of Coupling Inductances

In particular, in order to minimize the negative influence of the finite value of coupling inductance $L$ to the voltage response linearity, one can use shunting resistors $R_{SH}$ connected in parallel to these inductances. Due to the fact that impedance of the $RL$ circuit becomes low enough at Josephson oscillation frequency, the parallel array voltage response approaches the one for smaller and smaller inductance with decreasing $R_{SH}$ down to some optimal resistance value depending on the normalized inductance $l$. The further increase in $R_{SH}$ leads to some other linearity distortions. Therefore the most efficient way is the synthesis of an optimal SQIF structure with the cell area distribution $a(x)$ taking into account realistic finite values of $l$ found from the circuit layout. In this case, one should use a high performance numerical simulation technique (e.g., PSCAN [6]) for calculation of the SQIF voltage response $V(\Phi)$ in every cycle of the iterative algorithm (Fig. 2) which is to be used to solve master equation.

The shunting technique utility is confirmed by the results of numerical simulations presented in Fig. 6. One can see that at $R_{SH} \approx 0.1 R_N$ (where $R_N$ is Josephson junction normal resistance) voltage response of the parallel array of 6 junctions with $l = 2 \pi I_c L/\Phi_0 = 1$ nears to the one at vanishing coupling inductances. As a consequence, we observe the required linear voltage response of the differential scheme of two parallel SQIFs with $N = 20$ and coupling inductances $l = 1$ each shunted by resistor $R_{SH} = 0.1 R_N$.

IV. CONCLUSIONS

The differential scheme of two magnetically frustrated parallel SQIFs is developed to obtain highly linear single-peak voltage response. The response linearity can be increased up to 120 dB by finding the optimal SQIF cell area distribution using numerical simulations with realistic circuit parameters.
High linearity can be attainable for relatively small number of junctions. Such a circuit allows us to achieve high-performance in a two-dimensional serial-parallel SQIF-like array. Varying the number of elements connected in parallel and in series, one can set the impedance value needed to minimize the negative impact of the load. The synthesized structures can be used to design high-performance amplifiers and electrically small active antennas for megahertz and gigahertz frequency ranges.

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REFERENCES


